

P60B6SN

Power MOSFETs

60V, 60A, N-channel

Feature

- N-channel
- SMD
- Low Ron
- 10V Gate Drive
- Low Capacitance
- Pb free terminal
- RoHS:Yes

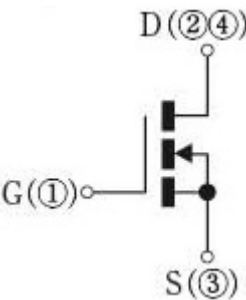
OUTLINE

Package (House Name): FB

Package (JEDEC Code): TO-252AA



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	Tstg		-55 to 150	°C
Channel tempertature	Tch		150	°C
Drain-source voltage	V _{DSS}		60	V
Gate-source voltage	V _{GSS}		±20	V
Continuous drain current(DC)	I _D		60	A
Continuous drain current(Peak)	I _{DP}	Pulse width 10μs, duty=1/100	180	A
Total power dissipation	P _T		62.5	W
Single avalanche current	I _{AS}	Starting Tch=25°C Tch≤150°C	33	A
Single avalanche energy	E _{AS}	Starting Tch=25°C Tch≤150°C	115	mJ

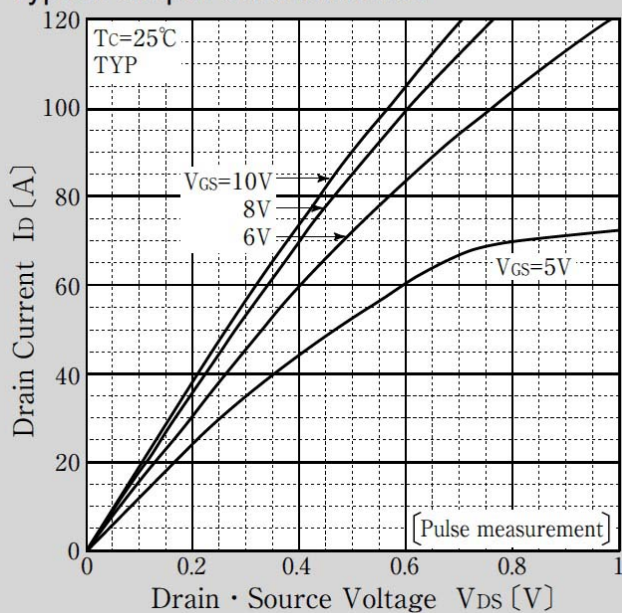
※ :See the original Specifications

Electrical Characteristics (unless otherwise specified : Tc=25°C)

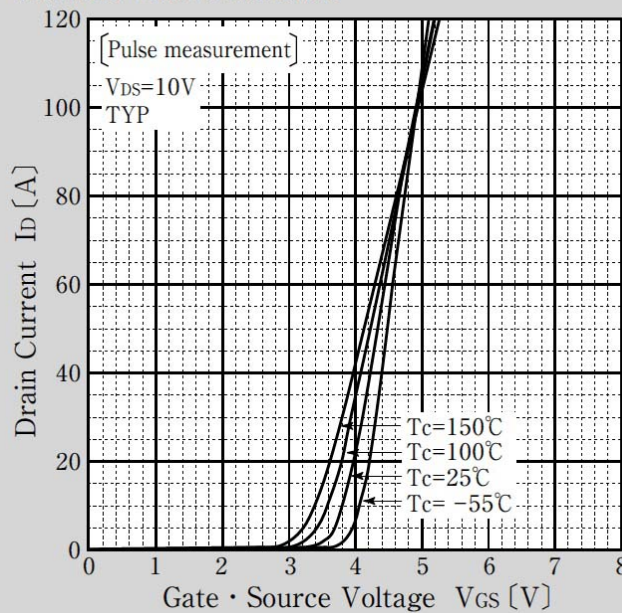
Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	ID=1mA, VGS=0V	60			V
Zero gate voltage drain current	I_{DSS}	VDS=60V, VGS=0V			1	μA
Gate-source leakage current	I_{GSS}	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	g_{fs}	ID=30A, VDS=10V	13	26		S
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=30A, VGS=10V		0.0053	0.0067	Ω
Gate threshold voltage	V_{th}	ID=1mA, VDS=10V	2	3	4	V
Source-drain diode forward voltage	V_{SD}	IS=60A, VGS=0V			1.5	V
Thermal resistance	$R_{th(j-c)}$	Junction to case			2	°C/W
Total gate charge	Q_g	VDD=48V, VGS=10V, ID=60A		55		nC
Gate to source charge	Q_{gs}	VDD=48V, VGS=10V, ID=60A		15		nC
Gate to drain charge	Q_{gd}	VDD=48V, VGS=10V, ID=60A		20		nC
Input capacitance	C_{iss}	VDS=25V, VGS=0V, f=1MHz		2780		pF
Reverse transfer capacitance	C_{rss}	VDS=25V, VGS=0V, f=1MHz		180		pF
Output capacitance	C_{oss}	VDS=25V, VGS=0V, f=1MHz		370		pF
Turn-on delay time	$t_{d(on)}$	ID=30A, RL=1Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		8		ns
Rise time	t_r	ID=30A, RL=1Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		26		ns
Turn-off delay time	$t_{d(off)}$	ID=30A, RL=1Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		30		ns
Fall time	t_f	ID=30A, RL=1Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		16		ns
Diode reverse recovery time	t_{rr}	IF=60A, VGS=0V, di/dt=100A/μs		43		ns
Diode reverse recovery charge	Q_{rr}	IF=60A, VGS=0V, di/dt=100A/μs		55		nC

※ :See the original Specifications

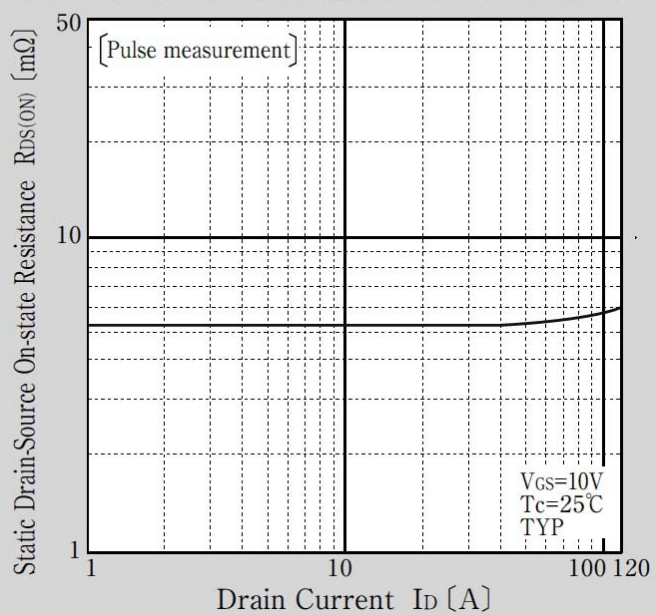
Typical Output Characteristics



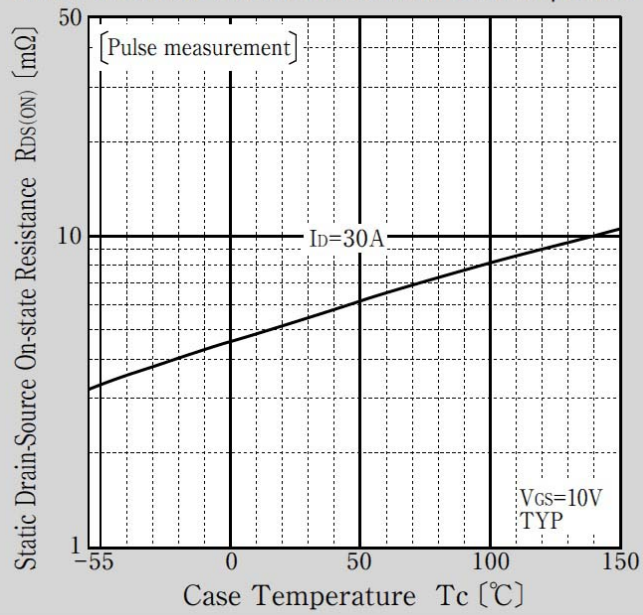
Transfer Characteristics



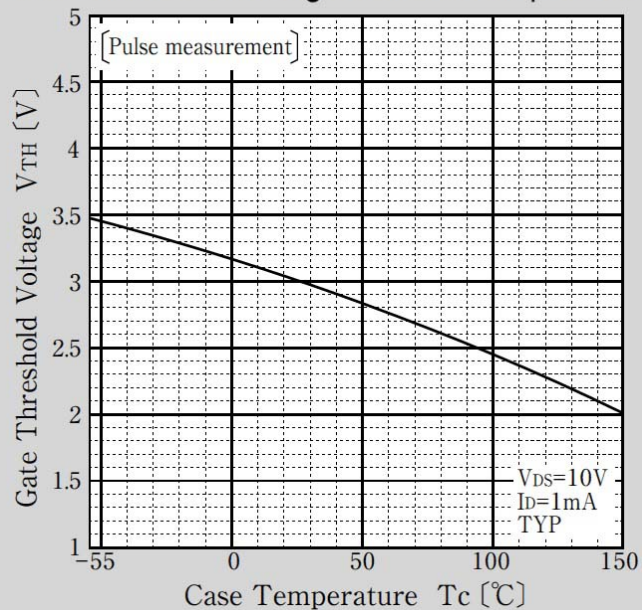
Static Drain-Source On-state Resistance vs Drain Current



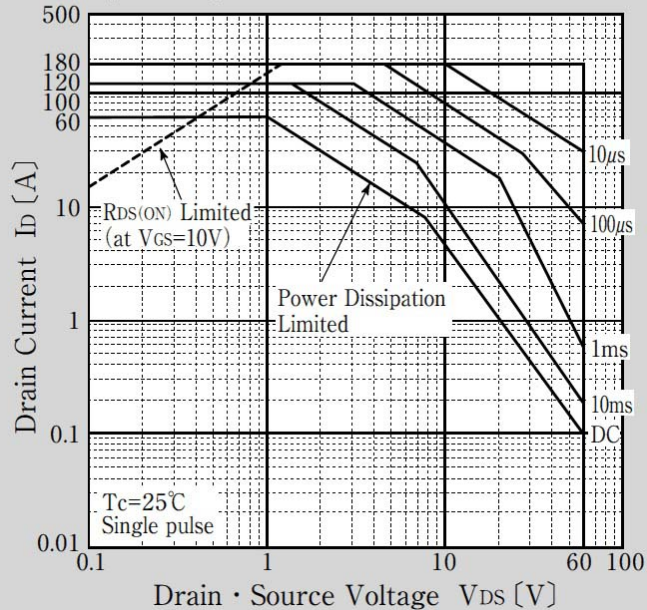
Static Drain-Source On-state Resistance vs Case Temperature



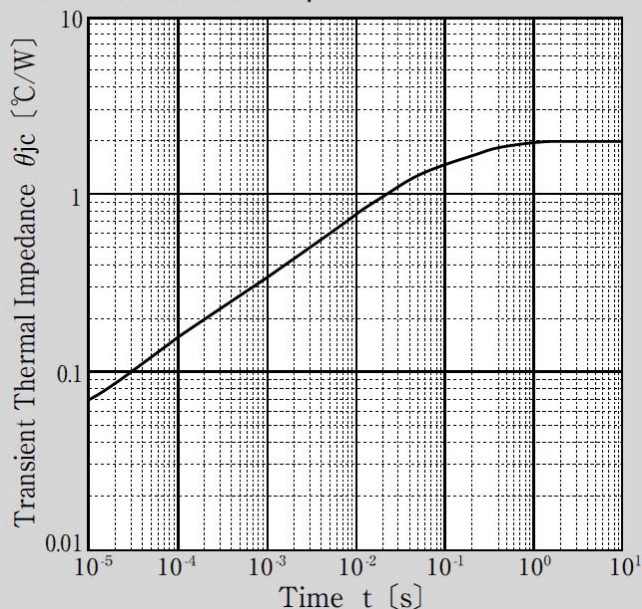
Gate Threshold Voltage vs Case Temperature



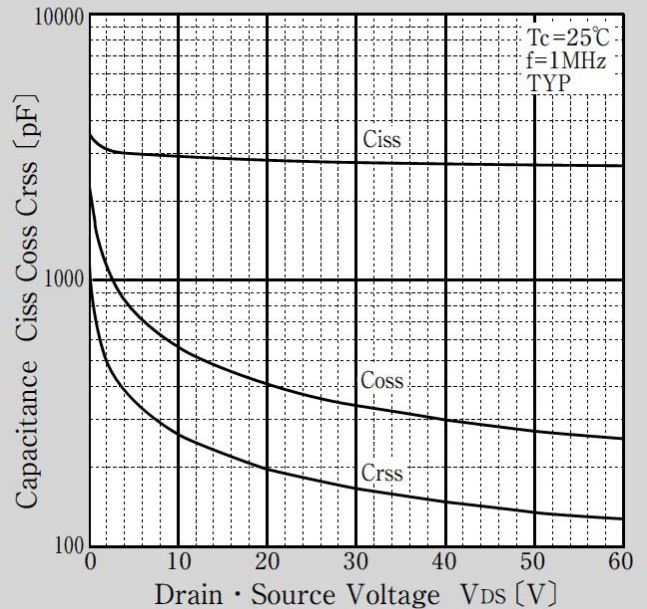
Safe Operating Area



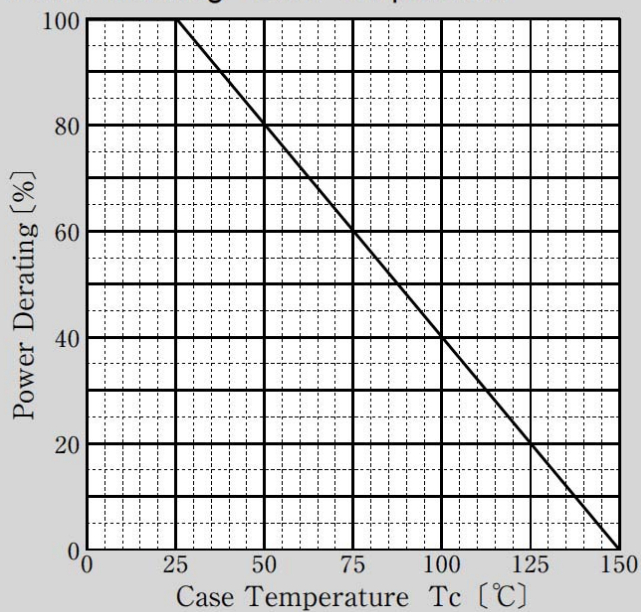
Transient Thermal Impedance



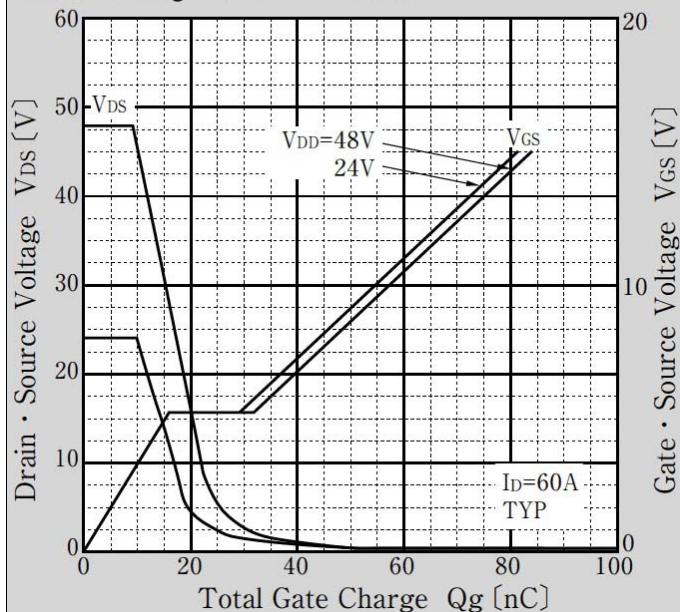
Capacitance Characteristics



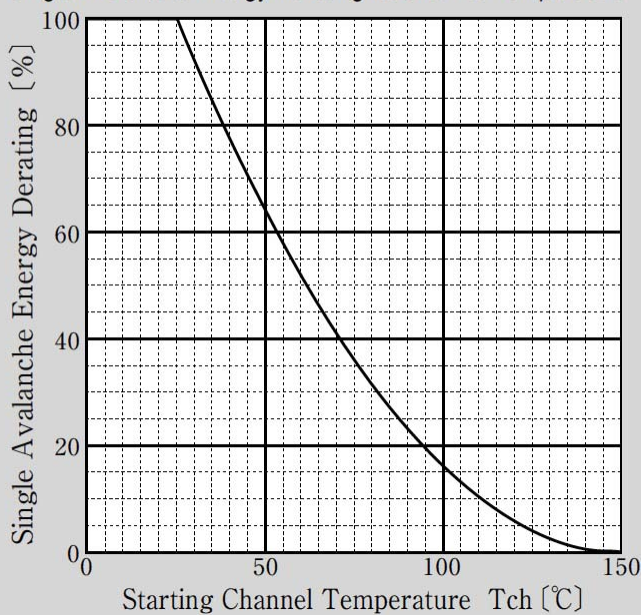
Power Derating - Case Temperature



Gate Charge Characteristics

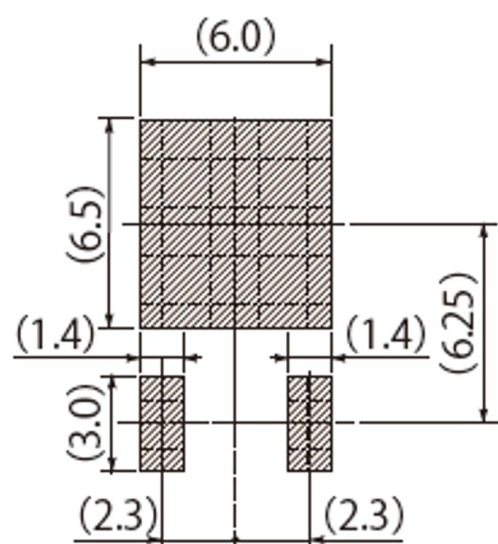
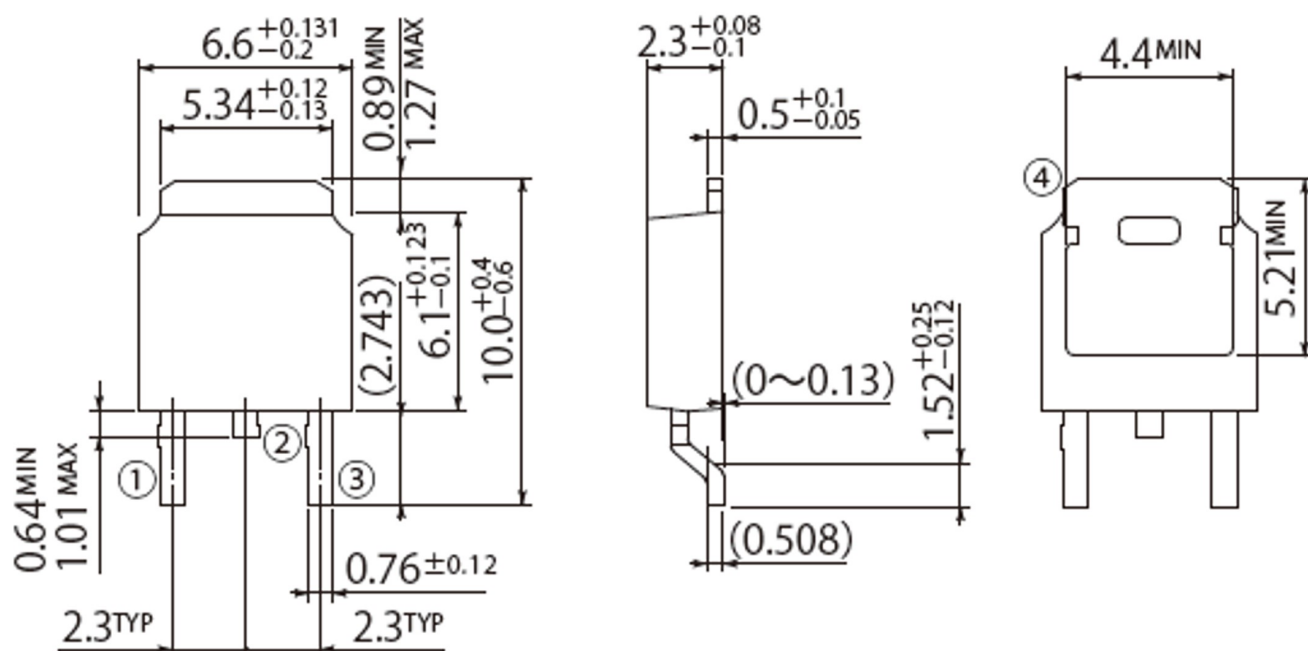


Single Avalanche Energy Derating vs Channel Temperature



G2

JEDEC Code	TO-252AA
JEITA Code	-
House Name	FB



Referential Soldering Pad

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